

74AHCT04 HEX INVERTERS

Description

The 74AHCT04 provides provides six independent inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

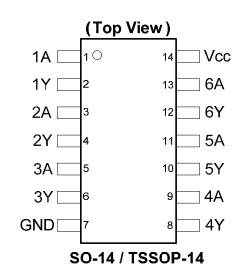
The gates perform the Boolean function:

 $Y = \overline{A}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

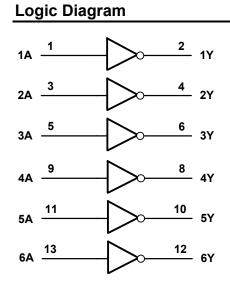
Click here for ordering information, located at the end of datasheet



74AHCT04

Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage



Function Table

Output
Y
Н
L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK} Input Clamp Current V _I < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O < 0V		-20	mA
I _{OK} Output Clamp Current V _O > V _{CC}		20	mA
I_{O} Continuous Output Current 0 V < V _O < V _{CC}		+/- 25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG} Storage Temperature		-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	Vcc	V
Δt/ΔV	Input transition Rise or Fall Rate		20	ns/V
T _A	Operating Free-Air Temperature	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol Parameter		Test Conditions	М	T _A = -40°C to +85°C		T _A = -40°C	to +125°C	Unit	
Symbol			Vcc	Min	Мах	Min	Max	Unit	
VIH	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V	
VIL	Low-Level Input Voltage		4.5V to 5.5V		0.8		0.8	V	
N/	High-Level Output	I _{OH} = -50μA	4.5V	4.4		4.4		V	
V _{OH} Voltage		I _{OH} = -8mA	4.5V	3.80		3.70		v	
N/	Low-Level Output	I _{OL} = 50μA	4.5V		0.1		0.1	V	
V _{OL}	Voltage	I _{OL} = 8mA	4.5V		0.44		0.55	v	
h	Input Current	VI = GND to 5.5V	3.6V		±1		±2	μA	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μA	
ΔI _{CC}	Additional Supply Current	One input at V_{CC} -2.1V Other pins at V_{CC} or GND	5.5V		1.35		5	mA	

Operating Characteristics

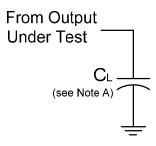
Parameter		Test Conditions	V _{CC} = 5.5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1MHz	14.8	pF
Ci	Input Capacitance	V _i = V _{CC} – or GND	4.0	pF

Switching Characteristics

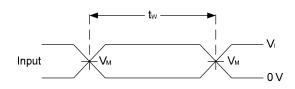
Symbol	Deremeter	Test	V	٦	r _A = +25°C	;	-40°C to	o +85°C	-40°C to	+125°C	l lmit
Symbol	Parameter	Conditions	V _{cc}	Min	Тур	Max	Min	Мах	Min	Max	Unit
	Propagation	Figure 1 C _L =15pF	4.5V to 5.5V	0.5	3.0	6.7	0.5	7.5	0.5	8.5	
t _{PD}	Delay A_N to Y_N	Figure 1 C _L = 50pF	4.5V to 5.5V	0.5	4.9	7.7	0.5	8.5	0.5	10.0	ns



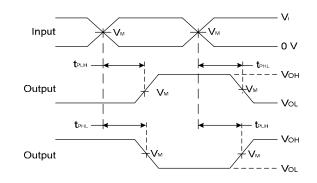
Parameter Measurement Information



N	Inputs		VM	VM	<u>^</u>
Vcc	VI	t _r /t _f	Inputs	Outputs	υL
4.5V to 5.5V	3.0V	3ns	1.5V	V _{CC} /2	15pF, 50pF



Voltage Waveform Pulse Duration



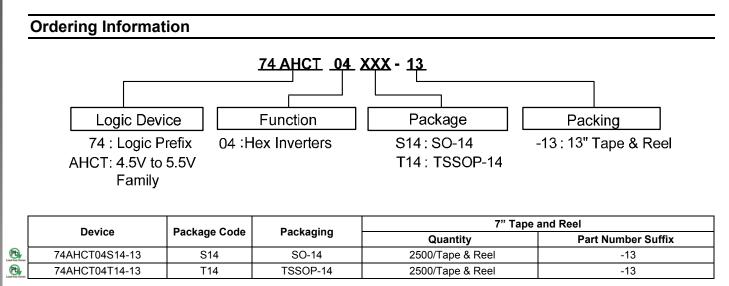
Voltage Waveform **Propagation Delay Times** Inverting and Non Inverting Outputs

Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

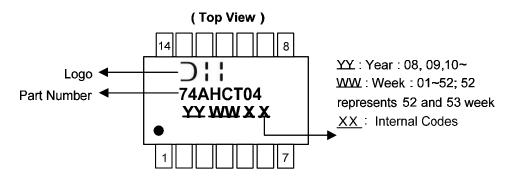
- B. All pulses are supplied at pulse repetition rate \leq 1 MHz. C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .





Marking Information

(1) SO-14, TSSOP-14



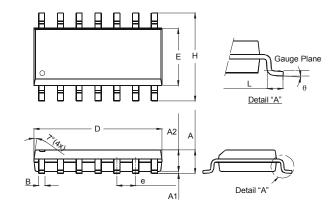
Part Number	Package
74AHCT04S14	SO-14
74AHCT04T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

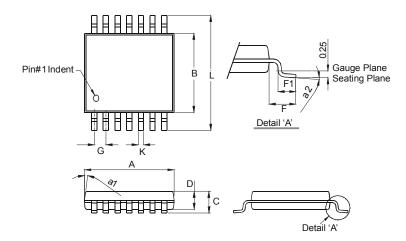
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45 Typ				
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Dir	nensions	in mm			

Package Type: TSSOP-14



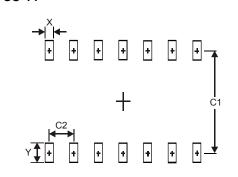
1	SSOP-1	4
Dim	Min	Max
a1	7° (4	4X)
a2	0°	8°
Α	4.9	5.10
в	4.30	4.50
C		1.2
D	0.8	1.05
F	1.00	Тур
F1	0.45	0.75
G	0.65	Тур
κ	0.19	0.30
L	6.40	Тур
All D	imensio	ns in
	mm	



Suggested Pad Layout

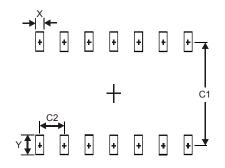
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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